

#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub> = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Maximum Repetitive Peak Reverse Voltage		V <sub>RRM</sub>	200	V	
Maximum RMS Voltage		Vrms	140	V	
Maximum DC Blocking Voltage		V <sub>DC</sub>	200	V	
Maximum Average Forward Current	per device		20	A	
	per diode	F(AV)	10		
Peak Forward Surge Current : 8.3 ms Single Half Sine- Wave Superimposed On Rated Load Per Diode		IFSM	170	A	
Typical Junction Capacitance		CJ	100	pF	
Measured at 1 MHZ And Applied $V_R = 4 V$			100		
Typical Thermal Resistance	(Note 1)	Rejc	6	°C/W	
	(Note 1)	Rejl	6.5		
Operating Junction Temperature Range		TJ	-55~175	٥C	
Storage Temperature Range		T <sub>STG</sub>	-55~175	٥C	



PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Forward Voltage Per Diode	VF	I <sub>F</sub> = 3 A, T <sub>J</sub> = 25 °C	-	0.79	-	V
		I <sub>F</sub> = 5 A, T <sub>J</sub> = 25 °C	-	0.83	-	V
		I <sub>F</sub> = 10 A, T <sub>J</sub> = 25 °C	-	-	0.95	V
		I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C	-	0.65	-	V
		I <sub>F</sub> = 5 A, T <sub>J</sub> = 125 °C	-	0.7	-	V
		I <sub>F</sub> = 10 A, T <sub>J</sub> = 125 °C	-	0.8	-	V
Reverse Current Per Diode	I <sub>R</sub>	V <sub>R</sub> = 160 V, T <sub>J</sub> = 25 °C	-	0.004	-	uA
		$V_R = 200 V, T_J = 25 \circ C$	-	-	1	
		V <sub>R</sub> = 200 V, T <sub>J</sub> = 125 °C	-	-	90	
Reverse Recovery Time	T <sub>RR</sub>	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>RR</sub> = 0.25 A, T <sub>J</sub> = 25 °C	-	-	35	ns
Reverse Recovery Time	T <sub>RR</sub>	I <sub>F</sub> = 10 A, V <sub>R</sub> = 200 V	-	30	-	ns
Peak Recovery Current	Irrm	di/dt = 300 A/uS	-	6.8	-	А
Reverse Recovery Charge	Q <sub>RR</sub>	T」 = 25 ℃	-	102	-	nC
Reverse Recovery Time	T <sub>RR</sub>	I <sub>F</sub> = 10 A, V <sub>R</sub> = 200 V	-	47	-	ns
Peak Recovery Current	Irrm	di/dt = 300A/uS	-	11	-	А
Reverse Recovery Charge	Qrr	T <sub>J</sub> = 125 °C	-	250	-	nC

NOTES :

1. Device mounted on a infinite heatsink.

**TYPICAL CHARACTERISTIC CURVES** 1000 12.5 C<sub>J</sub>, Junction Capacitance (pF) I<sub>F</sub>, Forward Current (A) 10 100 7.5 5 10 2.5 Per Diode Per Diode 1 0 0 40 80 120 160 200 100 125 150 175 0 25 50 75 V<sub>R</sub>, Reverse Bias Voltage (V) T<sub>C</sub>, Case Temperature (°C) **Fig.1 Forward Current Derating Curve Fig.2 Typical Junction Capacitance** 100 100 T<sub>J</sub> = 175°C Per Diode 10 T<sub>1</sub> = 150°C I<sub>F</sub>, Forward Current (A) T<sub>J</sub> = 175°C 10 T<sub>J</sub> = 125°C T<sub>J</sub> = 150°C T<sub>1</sub> = 100°C T<sub>J</sub> = 125°C 1 T<sub>.</sub> = 100°C T<sub>J</sub> = 25°C T<sub>J</sub> = 25°C 0.1 T<sub>J</sub> = -55°C T<sub>J</sub> = -55°C <u>ب</u> Per Diode 0.01 0.0001 0 0.3 0.6 0.9 1.2 1.5 20 40 60 80 100 Percent of Rated Reverse Voltage (%) V<sub>F</sub>, Forward Voltage (V) **Fig.3 Typical Reverse Characteristics Fig.4 Typical Forward Characteristics** 100 1000 T<sub>RR</sub> (nS) Q<sub>RR</sub> (nC) 100 I<sub>F</sub>=10A I<sub>F</sub>=10A V<sub>R</sub>=200V . V<sub>R</sub>=200V Per Diode

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T<sub>J</sub> = 125°C

100

150

Fig.5 Typical Reverse Recovery Time Versus di/dt

200

di/dt (A/uS)

10

50

MER2002FCT-REV.00

10

50

T<sub>J</sub> = 125°C

100

Per Diode

250

300

200

di/dt (A/uS)

150

Fig.6 Typical Reverse Recovery Charge Versus di/dt

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300

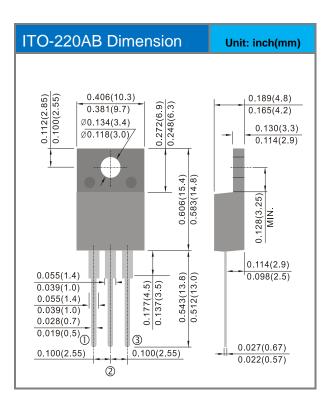
250



#### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
MER2002FCT_T0_00601	ITO-220AB	50pcs / Tube	MER2002FCT	Halogen free RoHS compliant

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